



ORIENT

Photo coupler

Product Data Sheet

Part Number: OR-355

Customer: _____

Date: _____

SHENZHEN ORIENT COMPONENTS CO.,LTD.

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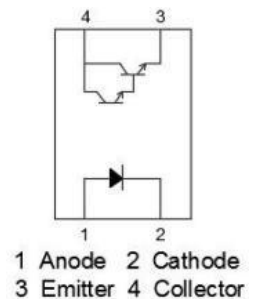
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1. Features

- (1) Current transfer ratio((CTR : MIN. 600% at $I_F = 1\text{mA}$, $V_{CE} = 2\text{V}$, $T_a = 25^\circ\text{C}$)
- (2) High input -output isolation voltage ($V_{ISO} = 3,750\text{Vrms}$)
- (3) High collector-emitter voltage ($V_{CEO} = 35\text{V}$)
- (4) Working Temperature -55°C to 110°C
- (5) SOP-4 package
- (6) Safety approval
 - UL approved(No.E323844)
 - VDE approved(No.40029733)
 - CQC approved (No.CQC19001231256)
- (7) In compliance with RoHS, REACH standards
- (8) MSL Class I



2. Instructions

- The OR-355 series device contains an infrared emitting diodes, optically to a photo Darlington detector.They are encapsulated in a 4 pin SOP encapsulation.
- Pin pitch of OR-355 is 2.54mm

3. Application Range

- Hybrid substrates that require high density mounting.
- Programmable controllers
- System appliance, measuring instruments

4. Max Absolute rated Value (Normal Temperature=25°C)

Parameter		Symbol	Rated Value	Unit
Input	Forward Current	I_F	50	mA
	Junction Temperature	T_J	125	°C
	Reverse Voltage	V_R	6	V
	Consume Power	P	100	mW
Output	Collector and emitter Voltage	V_{CEO}	35	V
	Emitter and collector Voltage	V_{ECO}	6	
	Collector Current	I_C	80	mA
	Consume Power	P_C	150	mW
Total Consume Power		P_{tot}	200	mW
*1 Insulation Voltage		V_{iso}	3750	Vrms
Working Temperature		T_{opr}	-55 to + 110	°C
Deposit Temperature		T_{stg}	-55 to + 125	
*2 Soldering Temperature		T_{sol}	260	

*1. AC Test, 1 minute, humidity = 40~60% Insulation test method as below:

- (1) Short circuit both terminals of photo coupler.
- (2) No Current when testing insulation voltage.
- (3) Adding sine wave voltage when testing.

*2. soldering time is 10 seconds.

5. Opto-electronic Characteristics

Parameter		Symbol	Min	Typ.*	Max	Unit	Condition
Input	Forward Voltage	V_F	---	1.1	1.4	V	$I_F=20\text{mA}$
	Reverse Current	I_R	---	---	5	μA	$V_R=5\text{V}$
	Terminal Capacitance	C_t	---	30	250	pF	$V=0$, $f=1\text{KHz}$
Output	Collector Dark Current	I_{CEO}	---	---	1	μA	$V_{CE}=20\text{V}$, $I_F=0$
	Collector-Emitter Breakdown Voltage	BV_{CEO}	35	---	---	V	$I_C=0.1\text{mA}$, $I_F=0$
	Emitter-Collector Breakdown Voltage	BV_{ECO}	6	---	---	V	$I_E=0.1\text{mA}$, $I_F=0$
Transforming Characteristics	1.Current Transfer Ratio	CTR	600	---	7500	%	$I_F=1\text{mA}$, $V_{CE}=2\text{V}$
	Collector Current	I_C	6	---	75	mA	
	Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	---	---	1	V	$I_F=20\text{mA}$, $I_C=5\text{mA}$
	Insulation Impedance	R_{iso}	5×10^{10}	1×10^{11}	---	Ω	DC500V 40~60%R.H.
	Floating Capacitance	C_f	---	0.6	1	pF	$V=0$, $f=1\text{MHz}$
	Response Time(Rise)	t_r	---	200	---	μs	$V_{CC}=5\text{V}$, $I_C=2\text{mA}$, $R_L=100\Omega$
	Descend Time(fall)	t_f	---	200	---	μs	

- Current Conversion Ratio = $I_C / I_F \times 100\%$

6. Rank table of current transfer ratio CTR (tolerance:±3%)

MODEL NO.	CTR Rank	Min.	Max.	Unit	Condition
OR-355	NO mark	600	7500	%	IF=1mA, V _{CE} =2V, Ta=25°C

7. Order Information

Part Number

OR-355-X-Y-Z

Note

X = Tape and reel option (TP or TP1).

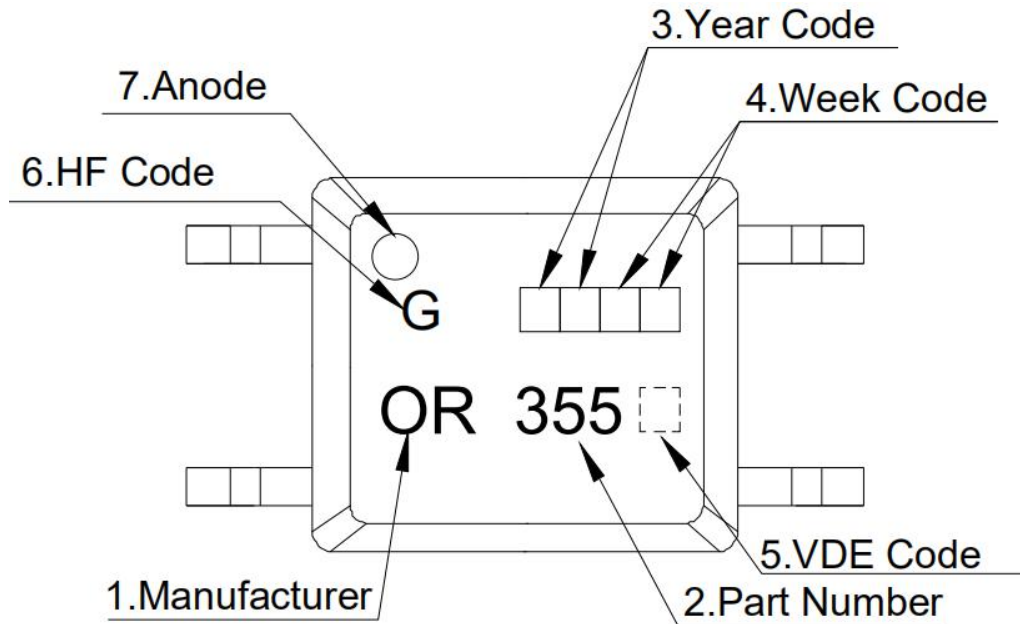
Y = ‘V’ code for VDE safety (This options is not necessary).

Z = ‘G’ code for Halogen free.

* VDE Code can be selected.

Option	Description	Packing quantity
TP	Surface mount lead form (low profile) + TP tape & reel option	3000 units per reel
TP1	Surface mount lead form (low profile) + TP1 tape & reel option	3000 units per reel

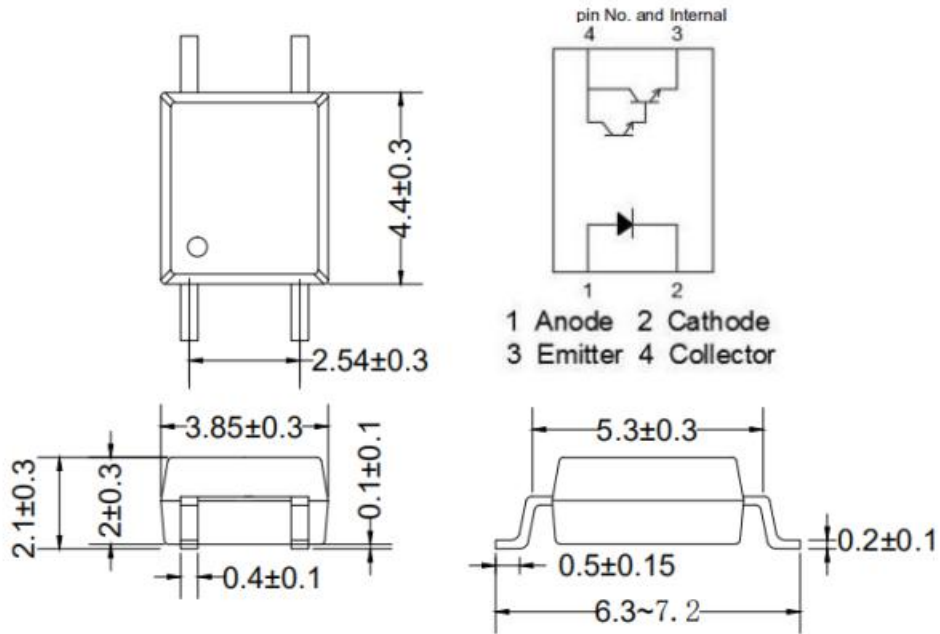
8. Naming Rule



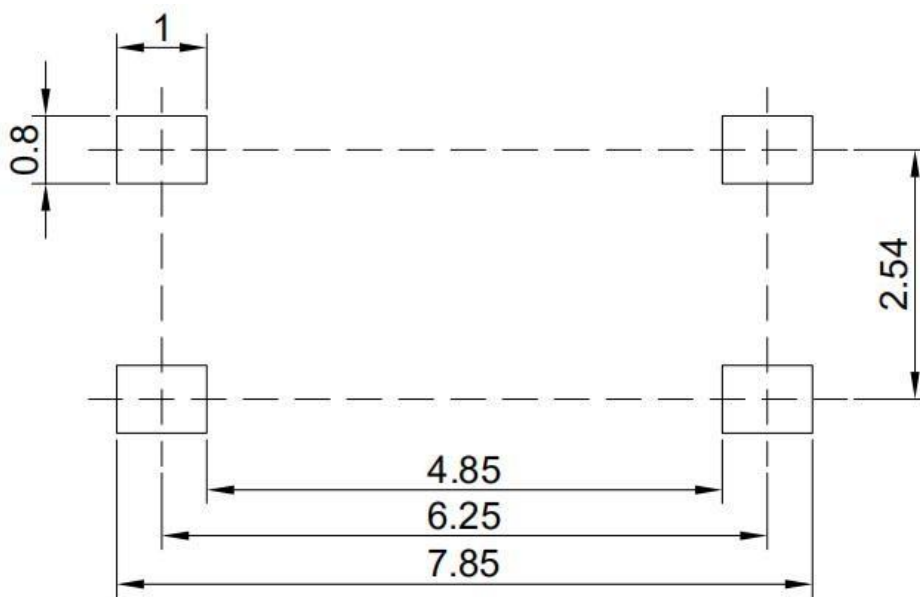
1. Manufacturer : ORIENT.
2. Part Number : 355.
3. Year Code : '21' means '2021' and so on.
4. Week Code : 01 means the first week, 02 means the second week and so on.
5. VDE Code . (Optional)
6. HF Code 'G': Halogen Free.
7. Anode.

* VDE Code can be selected.

9. Outer Dimension



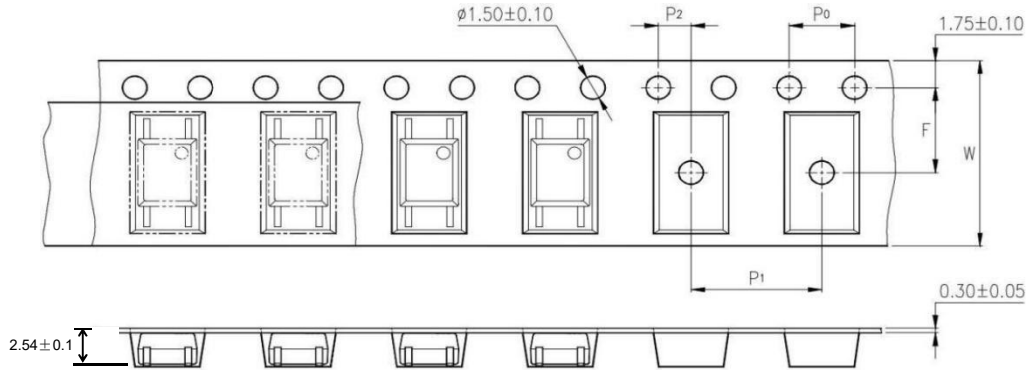
10. Recommended Foot Print Patterns (Mount Pad)



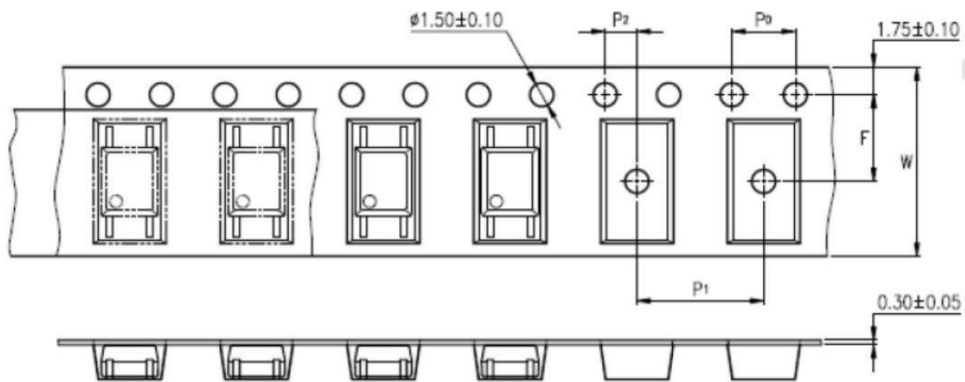
unit: mm

11. Taping Dimensions

(1) OR-355-TP



(2) OR-355-TP1



Description	Symbol	Dimension in mm(inch)
Tape wide	W	12±0.3 (0.472)
Pitch of sprocket holes	P0	4±0.1 (0.157)
Distance of compartment	F	5.5±0.1 (0.217)
	P2	2±0.1 (0.079)
Distance of compartment to compartment	P1	8±0.1 (0.315)

Package Type	TP/TP1
Quantities(pcs)	3000

12. Package Dimension

(1) package dimension

Packing Information	
Packing type	Reel type
Tape Width	12mm
Qty per Reel	3,000pcs
Small box (inner) Dimension	345*345*45mm
Large box (Outer) Dimension	480x360x360mm
Max qty per small box	6,000pcs
Max qty per large box	60,000pcs

(2)Packing Label Sample



Note:

1. Material Code :Product ID.
2. P/N :Contents with "Order Information" in the specification.
3. Lot No. :Product data.
4. D/C :Product weeks.
5. Quantity :Packaging quantity.

13. Reliability Test

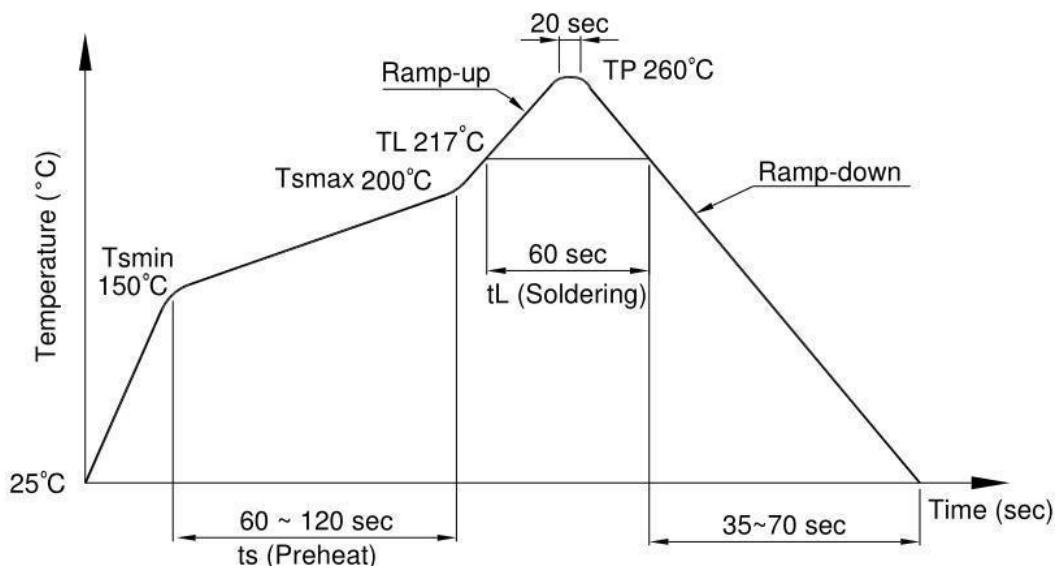
NO.	ITEMS	Reliability Testing				
		QTY. (Pcs)	Condition	Process	Device	Standard
1	RSH 耐焊接热	22	260±5℃	10s/3 次	锡炉	JESD22-A106
2	HTSL 高温存储	77	125℃	168 hrs	高温烤箱 测试仪	JESD22-A103
				500 hrs		
				1000 hrs		
3	LTSL 低温存储	77	-55℃	168 hrs	低温箱 测试仪	JESD22-A119
				500 hrs		
				1000 hrs		
4	TC 温度循环	77	H:125℃ 15min ∫ 5min L:-55℃ 15min	300 cycle	冷热冲击机	JESD22-A104
5	TS 温度冲击	77	H:100℃ 5min ∫ 15s L:-40℃ 5min	300 cycle	冷热冲击机	JESD22-A106
6	HTOL 高温操作	77	110℃ IF=10mA Vce=5V	168 hrs	高温烤箱 测试仪、老 化电路板	JESD22-A108
				500 hrs		
				1000 hrs		
7	ESD-HBM 人体模式	22	≥8KV 1Cycle	1次	ESD静电测 试仪	JESD22-A114
8	SD 可焊性	22	Pb-free 245±5℃	5S/1次	锡炉	JESD22-B102
9	HTRB 高温反向偏压	77	HTRB @125℃ Vce=80v	168 hrs	高温烤箱 , 测试仪	JESD22-A103
				500 hrs		
				1000 hrs		
10	H3TRB 温湿度反向偏 压, 寿命试验	77	H3TRB 85℃,85%RH Vce=80v	168 hrs	恒温恒湿 机, 测试仪	JESD22-A101
				500 hrs		
				1000 hrs		
11	Autoclave 压力锅	77	Ta=121 ℃,100%RH,2atm	96hrs	压力锅	JESD22-A102

14. Temperature Profile Of Soldering

(1) IR Reflow soldering (JEDEC-STD-020C compliant)

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.

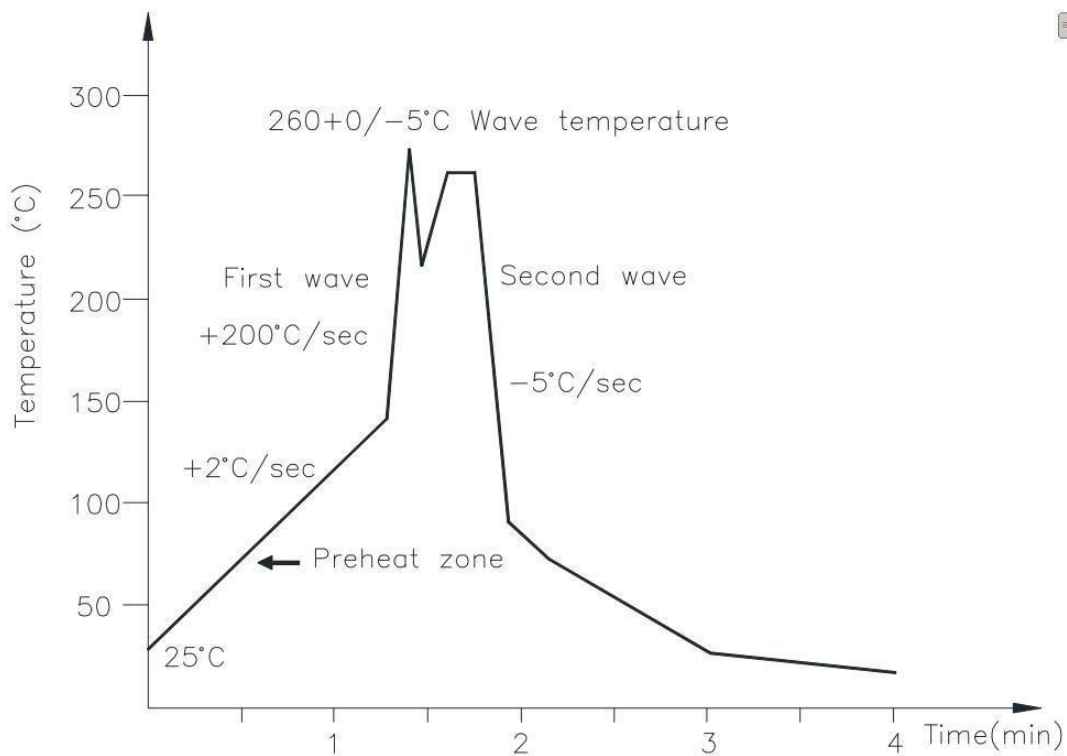
Profile item	Conditions
Preheat	
Temperature Min (T Smin)	150°C
Temperature Max (T Smax)	200°C
- Time (min to max) (ts)	90±30 sec
Soldering zone	
- Temperature (TL)	217°C
- Time (t L)	60 sec
Peak Temperature	260°C
Peak Temperature time	20 sec
Ramp-up rate	3°C / sec max.
Ramp-down rate from peak temperature	3~6°C / sec
Reflow times	≤3



(2) Wave soldering (JEDEC22A111 compliant)

One time soldering is recommended within the condition of temperature.

Temperature	260+0/-5°C
Time	10 sec
Preheat temperature	5 to 140°C
Preheat time	30 to 80 sec



(3) Hand soldering by soldering iron

Allow single lead soldering in every single process. One time soldering is recommended.

Temperature	380+0/-5°C
Time	3 sec max

15. Characteristics Curve

Figure 1. Diode Power Dissipation vs. Ambient Temperature

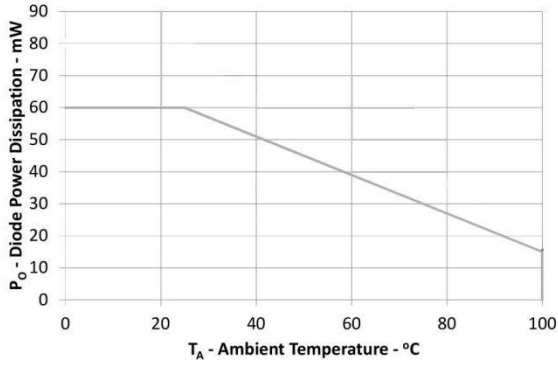


Figure 2. Transistor Power Dissipation vs. Ambient Temperature

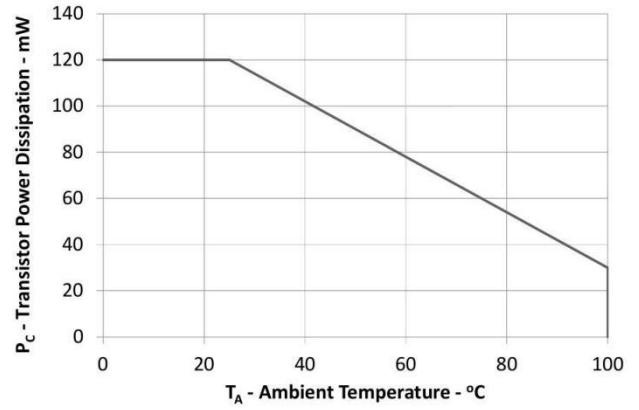


Figure 3. Forward Current vs. Forward Voltage

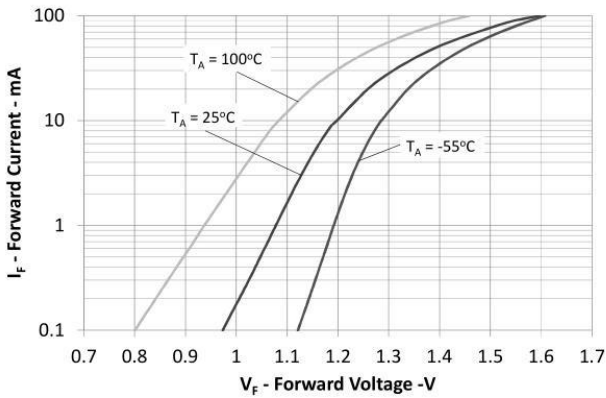


Figure 4. Collector Current vs. Non-Saturated Collector to Emitter Voltage

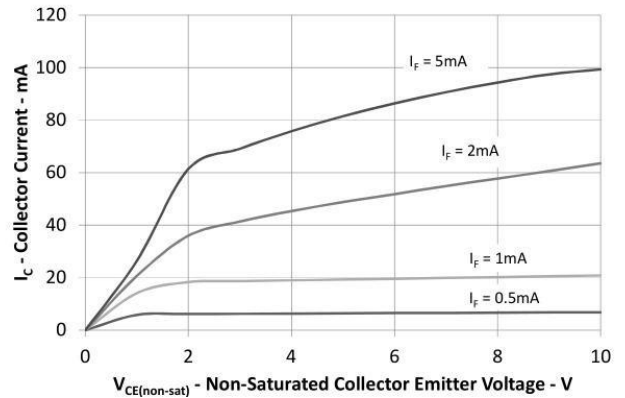


Figure 5. Collector to Emitter Dark Current vs. Ambient Temperature

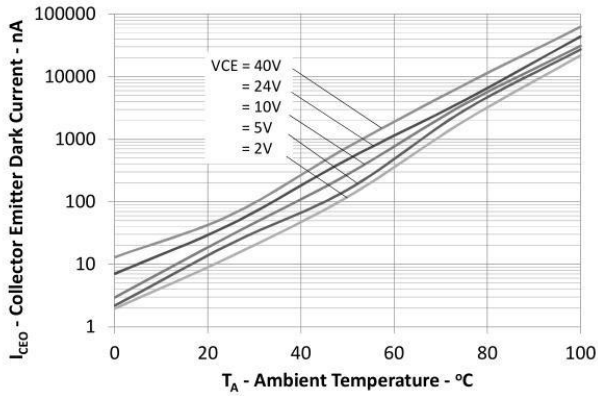


Figure 6. Collector Current vs. Saturated Collector to Emitter Voltage

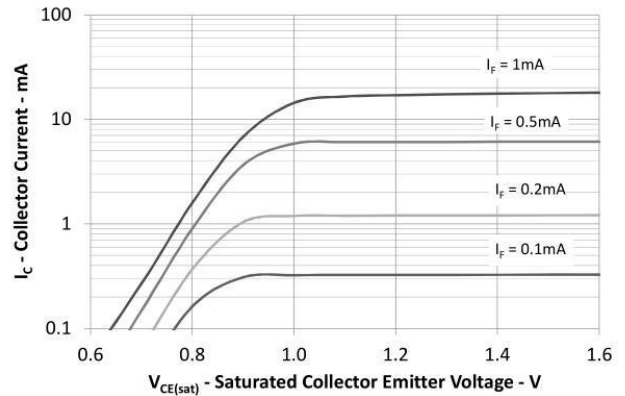


Figure 7. Normalized Current Transfer Ratio vs. Ambient Temperature

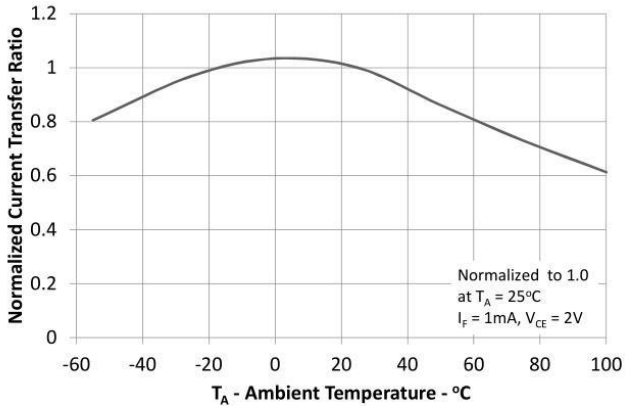


Figure 8. Current Transfer Ratio vs. Forward Current

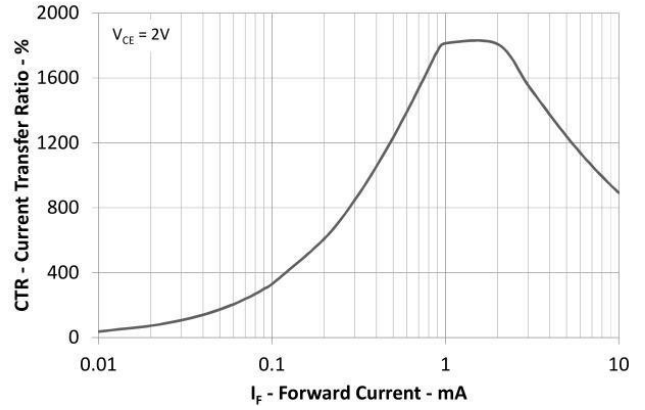


Figure 9. Switching Time vs. Load Resistance

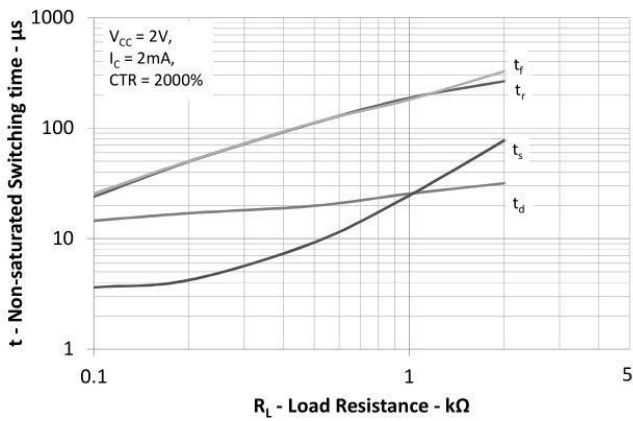


Figure 10. Switching Time vs. Load Resistance

